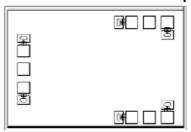
AMT1801 2 – 6GHz Power Divider Chip



Key Features:

Frequency range: 2 – 6GHz
Input/output standing wave: 1.3

Insertion loss: 0.6dBIsolation: 22dB

• Chip dimensions: 1.5mm x 1.0mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

Description:

AMT1801 is a 1-to-2 power divider chip designed by Gallium Arsenide (GaAs) process, it covers 2 – 6GHz frequency range, with 22dB typical isolation. This chip is designed with ground through metal vias on the back technology.

Absolute Maximum Ratings (Ta = 25°C)

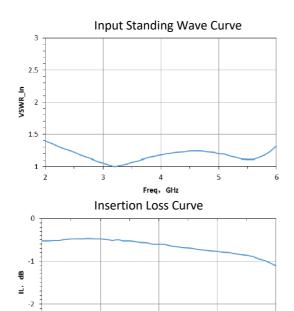
	<u> </u>		
Symbol	Parameter	Value	Remark
Pin	Input Power	+37dBm	
Tch	Operating Temperature	150°C	
Tm	Sintering Temperature	310°C	30s, N ₂ protection
Tstg	Storage Temperature	-65 ~ +150°C	

[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

Electrical Characteristics (Ta = 25°C)

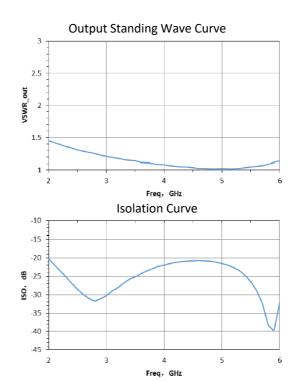
Symbol	Parameter	Test Conditions	Value		Unit	
			Min	Typical	Max	
VSWR_in	Input Standing Wave		-	1.3	1.6	-
VSWR_out	Output Standing Wave	Pin = 0 dBm	-	1.3	1.6	-
IL	Insertion Loss	F : 2 ~ 6GHz	-	0.6	1.35	dB
ISO	Isolation		17	22		dB

Typical Performance

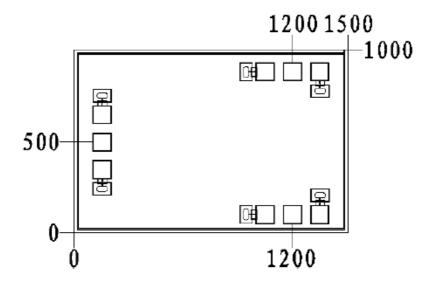


Freq, GHz

5



Chip Dimensions (Unit: μ m)



Chip Layout Diagram

